

HE8811

GaAlAs Infrared Emitting Diode

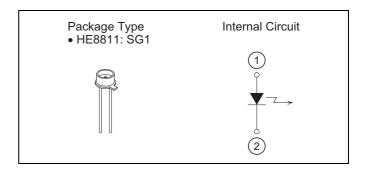
ODE-208-051 (Z) Rev.0 Oct. 30, 2006

Description

The HE8811 is a GaAlAs infrared emitting diode with a double heterojunction structure. It is high brightness, high output power and fast response make it suitable as a light source in measuring instruments and infrared-beam communication equipment.

Features

- High-frequency response
- High efficiency and high output power
- Broad radiation pattern



Absolute Maximum Ratings

 $(T_C = 25^{\circ}C)$

Item	Symbol Ratings		Unit
Forward current	I _F	200	mA
Reverse voltage	V_R	3	V
Operating temperature	Topr	-20 to +60	°C
Storage temperature	Tstg	-40 to +90	°C

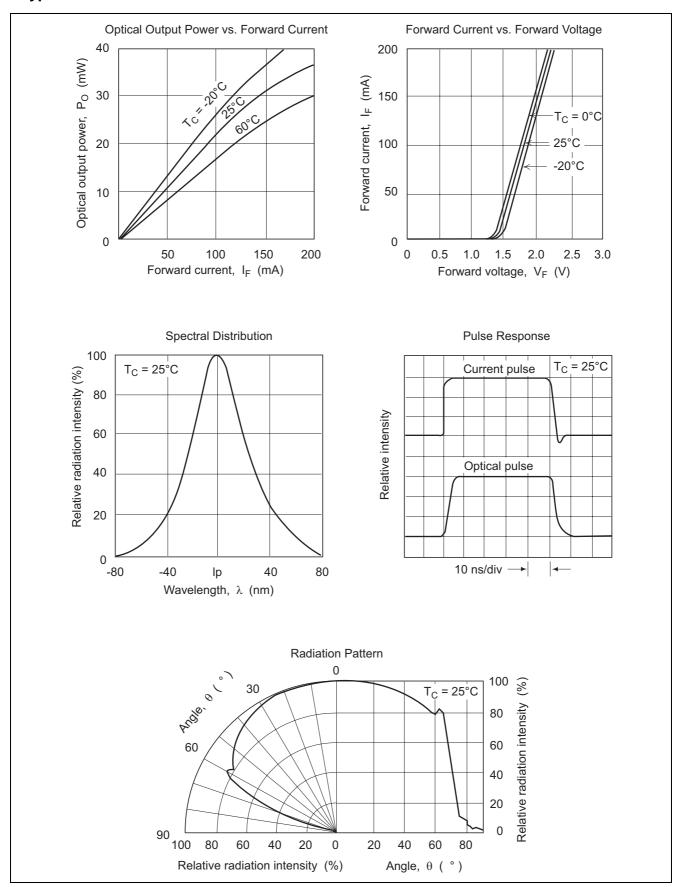
Optical and Electrical Characteristics

 $(T_C = 25^{\circ}C)$

ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Optical output power	Po	20	30		mW	I _F = 150 mA
Peak wavelength	λρ	780	820	900	nm	I _F = 150 mA
Spectral width	Δλ		50		nm	I _F = 150 mA
Forward voltage	V_{F}			2.5	V	I _F = 150 mA
Reverse current	I _R			100	μΑ	V _R = 3 V
Capacitance	Ct		10		pF	$V_R = 0 V$, $f = 1 MHz$
Rise time	t _r	1	5	1	ns	$I_F = 50 \text{ mA}$
Fall time	t _f	_	7	_	ns	$I_F = 50 \text{ mA}$



Typical Characteristic Curves



Package Dimensions

As of July, 2002 Unit: mm ϕ 5.4 ± 0.2 0.65 ± 0.2 $\phi 4.65 \pm 0.2$ $\phi 4.0 \pm 0.2$ 0.55 ± 0.2 14 ± 2 2 Đ Ø 0.45 ± 0.1 2.54 ± 0.35 2 $(2 - \phi 1.05)$ OPJ Code JEDEC IR/SG1 JEITA Mass (reference value) 0.25 g



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- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.
 - When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.
- 3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

Sales Offices



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For the detail of Opnext, Inc., see the following homepage:

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